L Number	Hits	Search Text	DB	Time stamp
	603	(345/82-83).CCLS.	USPAT;	2002/07/18 14:34
1			EPO; JPO;	
			IBM_TDB	
-	824	(345/76-81).CCLS.	USPAT;	2002/07/15 14:28
			EPO; JPO;	
			IBM_TDB	
-	11911	(current or voltage) near5 color	USPAT;	2002/07/15 14:40
			EPO; JPO;	
			IBM_TDB	
-	73	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and ((current or voltage)	USPAT;	2002/07/15 14:39
		near5 color)	EPO; JPO;	
			IBM_TDB	
-	2	("3740570").PN.	USPAT;	2002/07/15 14:32
			EPO; JPO;	
			IBM_TDB	
-	25994	(TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:22
			EPO; JPO;	
			IBM_TDB	
-	113	((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	USPAT;	2002/07/15 14:41
		color)	EPO; JPO;	
			IBM_TDB	
-	1	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and (((TFT or (thin adj	USPAT;	2002/07/15 14:39
		film adj transistor))) same ((current or voltage) near5 color))	EPO; JPO;	
			IBM_TDB	
-	6107	((current or voltage near2 control)) near5 color	USPAT;	2002/07/15 14:46
ļ			EPO; JPO;	
			IBM_TDB	
-	20	((TFT or (thin adj film adj transistor))) same (((current or voltage near2	USPAT;	2002/07/15 14:48
		control)) near5 color)	EPO; JPO;	
			IBM_TDB	
-	715	((current or voltage) near2 control) near5 color	USPAT;	2002/07/15 14:48
			EPO; JPO;	
			IBM_TDB	
-	4	((TFT or (thin adj film adj transistor))) same (((current or voltage) near2	USPAT;	2002/07/15 14:48
		control) near5 color)	EPO; JPO;	
			IBM_TDB	
-	2	jp-10039791-\$.did.	EPO; JPO;	2002/07/17 10:45
		1000 104155 775 477	DERWENT	
-	1	1998-184157.NRAN.	DERWENT	2002/07/17 10:46
-	896	(TFT or (thin adj film adj transistor)) near5 size	USPAT;	2002/07/17 13:33
			EPO; JPO;	
	17	(HATIN II - WHAT AT A HO	IBM_TDB	
•	16	("W/L" or "W adj L") same ((TFT or (thin adj film adj transistor)) near5	USPAT;	2002/07/17 13:33
		size)	EPO; JPO;	
	2	ID 00226700 © 4:4	IBM_TDB	2002/05/15 15 15
•	2	JP-09236790-\$.did.	EPO; JPO;	2002/07/17 13:29
	12407	("M//I " or ("M/" od: "I "))	DERWENT	2002/05/15 15 5
•	12497	("W/L" or ("W" adj "L"))	USPAT;	2002/07/17 13:34
			EPO; JPO;	1
	107	(TET on (ALin add Classadia and Control of C	IBM_TDB	
-	127	(TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L")))	USPAT;	2002/07/17 13:33
			EPO; JPO;	
	17	("W/I" = 0 ("W/" o 4: H1 !!)) (/TPT - /4!	IBM_TDB	
-	16	("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 13:34
		near5 size)	EPO; JPO;	ł
	^	((BAV/I II on (BAVIII - 1: III III)) - ((DDDD (41: 1) C) - (1: 1)	IBM_TDB	
-	0	(("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 13:34
		near5 size)) not (("W/L" or "W adj L") same ((TFT or (thin adj film adj	EPO; JPO;	
	2	transistor)) near5 size))	IBM_TDB	
-	2	((TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L"))))	USPAT;	2002/07/17 13:35
-		same color	EPO; JPO;	
	i	<u> </u>	IBM_TDB	L

-	1	("4810060").PN.	USPAT; EPO; JPO; IBM TDB	2002/07/17 14:25
-	6	("4600274" "4601546" "4716403" "4728172" "4728175" "4761058").PN.	USPAT	2002/07/17 14:25
_	15	4810060.URPN.	USPAT	2002/07/17 14:26
_	2	(TFT or (thin adj film adj transistor)) same (emission adj efficiency)	USPAT;	2002/07/18 09:24
	_	(EPO; JPO;	
			IBM TDB	
0. —	537	(TFT or (thin adj film adj transistor)) same (electroluminescence or "EL")	USPAT;	2002/07/17 15:27
	'		EPO; JPO;	
/			IBM TDB	
-	129	(TFT or (thin adj film adj transistor)) same (electroluminescence)	USPĀT;	2002/07/17 15:27
			EPO; JPO;	
			IBM_TDB	
-	20	(TFT or (thin adj film adj transistor)) same (electroluminescence adj	USPAT;	2002/07/17 15:35
		element)	EPO; JPO;	
			IBM_TDB	
-	3250	switching near3 (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:37
			EPO; JPO;	
	ĺ		IBM_TDB	
-	2161	driving near3 (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:38
ļ			EPO; JPO;	
			IBM_TDB	
-	230	(switching near3 (TFT or (thin adj film adj transistor))) same (driving	USPAT;	2002/07/17 15:37
	ļ	near3 (TFT or (thin adj film adj transistor)))	EPO; JPO;	
			IBM_TDB	
-	171	(switching near3 (TFT or (thin adj film adj transistor))) with (driving	USPAT;	2002/07/17 15:37
ļ		near3 (TFT or (thin adj film adj transistor)))	EPO; JPO;	
İ		the state of the s	IBM_TDB	2000/07/17 15 20
-	401	switching adj (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:38
}			EPO; JPO;	
	478	driving adj (TFT or (thin adj film adj transistor))	IBM_TDB USPAT;	2002/07/17 15:38
-	4/6	diving adj (11 1 of (dilif adj film adj transistor))	EPO; JPO;	2002/07/17 15.56
			IBM_TDB	
_	17	(switching adj (TFT or (thin adj film adj transistor))) same (driving adj	USPAT;	2002/07/17 15:38
	'	(TFT or (thin adj film adj transistor)))	EPO; JPO;	
		((IBM TDB	
-	26028	(TFT or (thin adj film adj transistor))	USPAT;	2002/07/18 09:23
		(,	EPO; JPO;	
	ł		IBM_TDB	
-	62	((TFT or (thin adj film adj transistor))) and (emission adj efficiency)	USPAT;	2002/07/18 09:24
			EPO; JPO;	
			IBM_TDB	
-	214	((TFT or (thin adj film adj transistor))) and (chromaticity)	USPAT;	2002/07/18 09:25
			EPO; JPO;	
1			IBM_TDB	
-	3	1 (((USPAT;	2002/07/18 09:25
		and (((TFT or (thin adj film adj transistor))) and (chromaticity))	EPO; JPO;	
		///	IBM_TDB	************
-	2	("5550066" "5684365").PN.	USPAT	2002/07/18 09:29
-	2	("6204610").PN.	USPAT;	2002/07/18 10:24
	1 .	2000 (5120(ND AN	DERWENT	2002/07/19 10 25
-	1	2000-651206.NRAN.	DERWENT	2002/07/18 10:25
-	1	("5684365").PN.	USPAT;	2002/07/18 10:57
			EPO; JPO; IBM_TDB	
	1	("6072272").PN.	USPAT;	2002/07/18 12:02
	'	COULTE J.I IV.	EPO; JPO;	2002/07/10 12.02
			IBM_TDB	
.	8	("4193015" "4220892" "5045750" "5311337" "5317437"	USPAT	2002/07/18 11:49
		"5467422" "5565754" "5654729").PN.	001711	2002/07/10 11:49
_	0	6072272.URPN.	USPAT	2002/07/18 11:50
		· · · · · · · · · · · · · · · · · · ·	4	

•	2	("6366025").PN.	USPAT;	2002/07/18 12:02
			EPO; JPO;	
			DERWENT	i
-	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:02
-	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:04
-	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:05
-	1	("6072272").PN.	USPAT;	2002/07/18 15:04
			EPO; JPO;	
			IBM_TDB	
-	1	("6121726").PN.	USPĀT;	2002/07/18 15:04
			EPO; JPO;	
			IBM TDB	